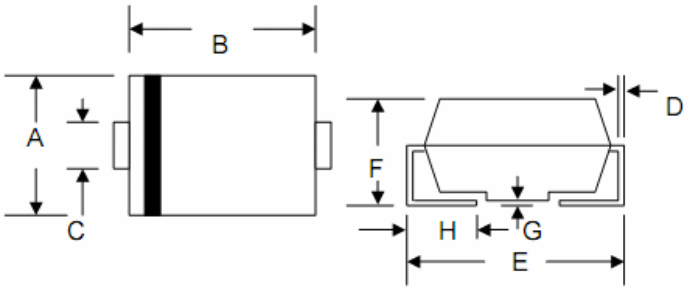
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Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 100A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



SMC/DO-214AB				
Dim	Min	Max	Min	Max
A	5.59	6.22	0.220	0.245
B	6.60	7.11	0.260	0.280
C	2.75	3.25	0.108	0.128
D	0.15	0.31	0.006	0.012
E	7.75	8.13	0.305	0.320
F	2.00	2.62	0.079	0.103
G	0.05	0.20	0.002	0.008
H	0.76	1.27	0.030	0.050
	In mm		In inch	

Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)

Marking Diagram:



Where XXXXX is YYWWL

SK32 = Part Name
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK32-G-SK310-G	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	SK32-G	SK33-G	SK34-G	SK35-G	SK36-G	SK38-G	SK39-G	SK310-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	30	40	50	60	80	90	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @T_L = 75°C	I_O	3.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100								A
Forward Voltage @I_F = 3.0A	V_{FM}	0.55			0.75		0.85			V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	0.5 20								mA
Typical Thermal Resistance Junction to Ambient (Note 1)	$R_{\theta JA}$	55								K/W
Operating Temperature Range	T_j	-65 to +125								°C
Storage Temperature Range	T_{STG}	-65 to +150								°C

Note: 1. Mounted on P.C. Board with 14mm^2 copper pad areas

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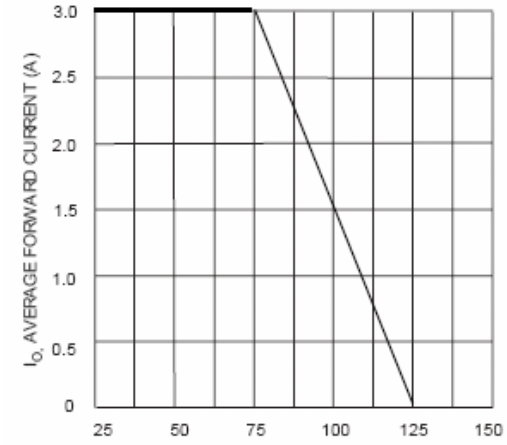


Fig. 1 Forward Current Derating Curve

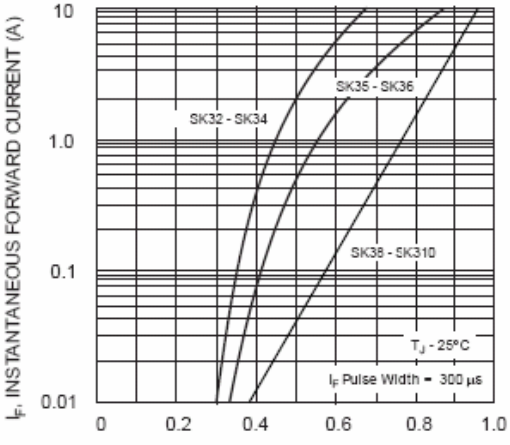
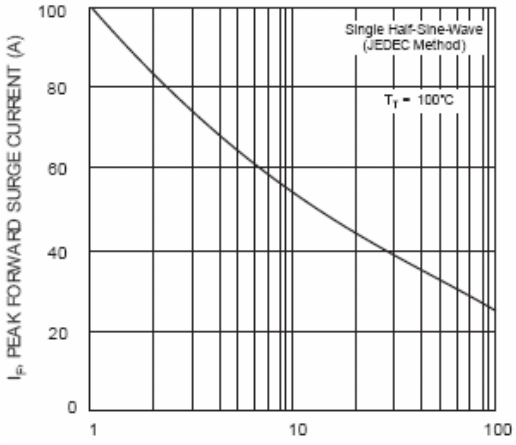


Fig. 2 Typical Forward Characteristics



Fi . 3 Max Non-Repetitive Peak Fwd Sur e Current

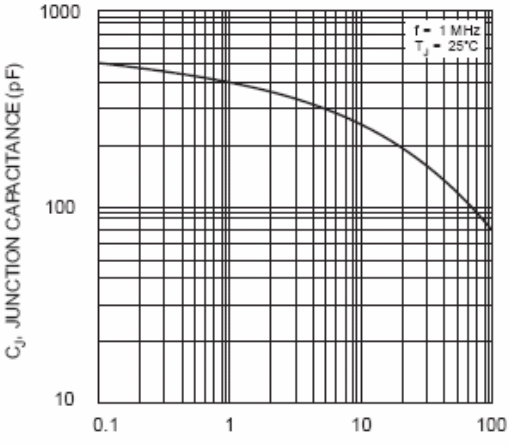


Fig. 4 Typical Junction Capacitance

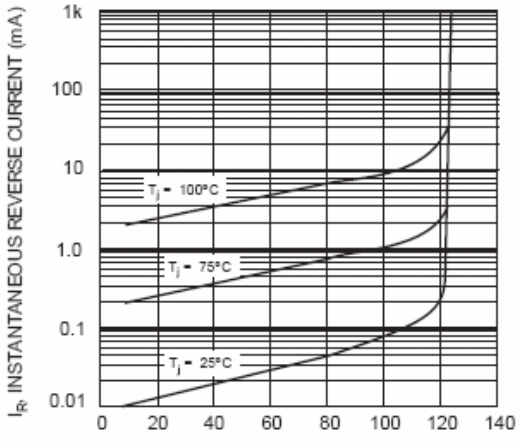


Fig. 5 Typical Reverse Characteristics

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